

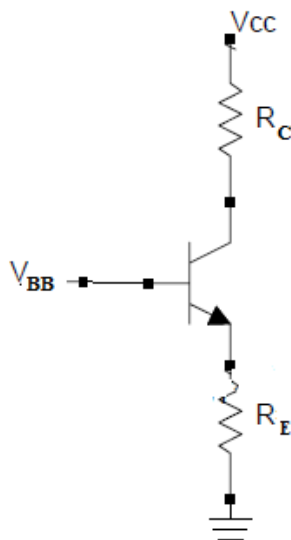
19EEE111: Numerical Questions

Zener Diode

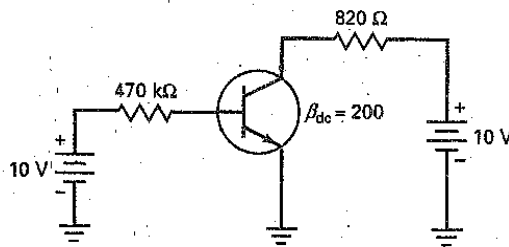
1. A 5.0V stabilised power supply is required to be produced from a 12V DC power supply input source. The maximum power rating P_Z of the zener diode is 2W. Using the zener regulator circuit above calculate:
 - a. The maximum current flowing through the zener diode.
 - b. The minimum value of the series resistor, R_S
 - c. The load current I_L if a load resistor of $1k\Omega$ is connected across the zener diode.
 - d. The zener current I_Z at full load.

Transistor

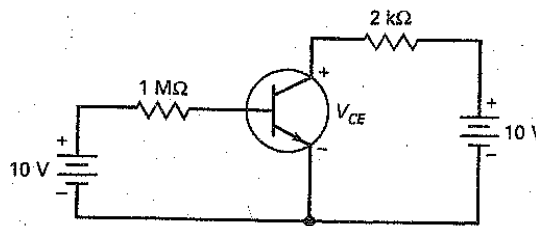
2. In the NPN transistor, 10^8 holes/ μs move from the base to the emitter region while 10^{10} electrons/ μs move from the emitter to the base region. An ammeter reads the base current as $i_B = 16\mu A$. Determine the emitter current i_E and the collector current i_C .
3. Given that
 - a. Given $\alpha = 0.987$, determine the corresponding value of β .
 - b. Given $\beta = 120$, determine the corresponding value of α .
 - c. Given $\beta = 180$ and $I_C = 2.0$ mA, find I_E and I_B .
4. A bipolar NPN transistor has a DC current gain, (Beta) value of 200. Calculate the base current I_B required to switch a resistive load of 4mA.
5. An NPN Transistor has a DC base bias voltage, V_B of 10v and an input base resistor, R_B of $100k\Omega$. What will be the value of the base current into the transistor?
6. What is the collector voltage in the given Figure? Also find the emitter voltage. Find the Q point. Given $V_{BB} = 2.5$ V; $V_{CC} = 20$ V, $R_E = 1.8$ kOhm, $R_C = 10$ kOhm.



7. If the $470\text{ k}\Omega$ resistor has a tolerance of $\pm 5\%$ then what is the maximum base current?



8. Transistor shown in the figure has $\beta = 300$ find, I_B

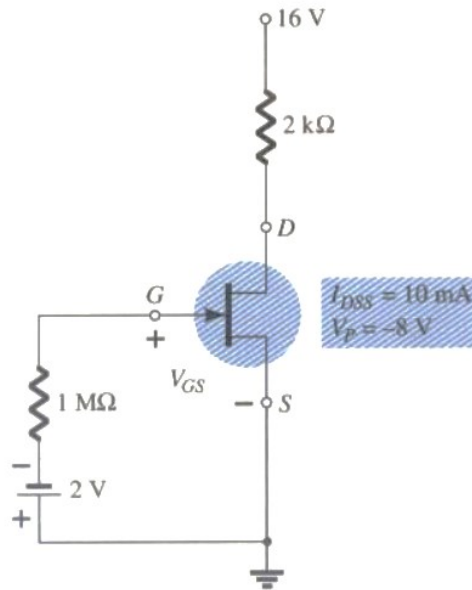


Transistor as a Switch

9. Using the transistor values of: $\beta = 200$, $I_c = 4\text{mA}$ and $I_b = 20\mu\text{A}$, find the value of the Base resistor (R_b) required to switch the load fully “ON” when the input terminal voltage exceeds 2.5V .
10. Using the transistor values of : $\beta = 200$, find the minimum Base current required to turn the transistor “fully-ON” (saturated) for a load that requires 200mA of current when the input voltage is increased to 5.0V . Also calculate the new value of R_b .

Junction Field Effect Transistor

11. For the JFET Circuit shown below Determine the following : V_{GS} , I_D , V_{DS} , V_D , V_G , V_S



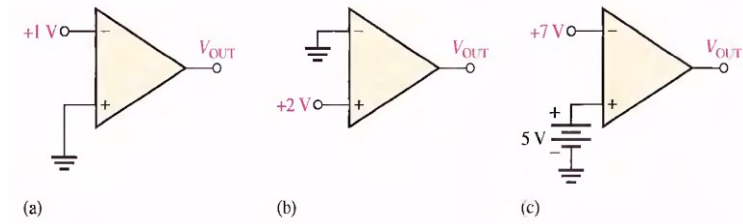
12. An n channel JFET has a drain current of 5 mA. OF $I_{DSS} = 10\text{mA}$ and $V_{GS}(\text{off}) = -6\text{V}$. Find the value of
- V_{GS} (Gate to Source Voltage)
 - V_p

Light Emitting Diode

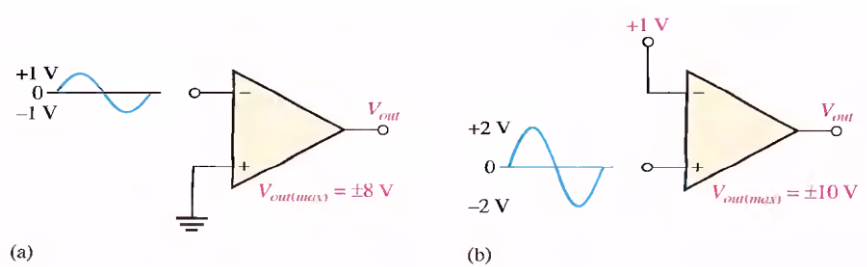
13. An amber coloured LED with a forward volt drop of 2 volts is to be connected to a 5.0v stabilised DC power supply. Using the circuit above calculate the value of the series resistor required to limit the forward current to less than 10mA. Also calculate the current flowing through the diode if a 100Ω series resistor is used instead of the calculated first.
- Series resistor required at 10mA.
 - with a 100Ω series resistor.

Operational Amplifiers

14. Determine the output level (maximum positive or maximum negative) for each comparator in Figure.



15. Draw the output voltage waveform for each circuit in Figure with respect to the input. Show voltage levels.



Answer Key

Zener Diode

1. Using the zener regulator circuit above calculate:
 - a. The maximum current flowing through the zener diode.
 - b. The minimum value of the series resistor, R_S
 - c. The load current I_L if a load resistor of $1k\Omega$ is connected across the zener diode.
 - d. The zener current I_Z at full load¹.

- a). The maximum current flowing through the zener diode.

$$\text{Maximum Current} = \frac{\text{Watts}}{\text{Voltage}} = \frac{2w}{5v} = 400mA$$

- b). The minimum value of the series resistor, R_S

$$R_S = \frac{V_S - V_Z}{I_Z} = \frac{12 - 5}{400mA} = 17.5\Omega$$

- c). The load current I_L if a load resistor of $1k\Omega$ is connected across the zener diode.

$$I_L = \frac{V_Z}{R_L} = \frac{5v}{1000\Omega} = 5mA$$

- d). The zener current I_Z at full load.

$$I_Z = I_S - I_L = 400mA - 5mA = 395mA$$

¹ Source : https://www.electronics-tutorials.ws/diode/diode_7.html

Transistor

2. Ans:

The emitter current is found as the net rate of flow of positive charge into the emitter region:

$$\begin{aligned}i_E &= (1.602 \times 10^{-19} \text{ C/hole})(10^{14} \text{ holes/s}) - (-1.602 \times 10^{-19} \text{ C/electron})(10^{16} \text{ electrons/s}) \\&= 1.602 \times 10^{-5} + 1.602 \times 10^{-3} = 1.618 \text{ mA}\end{aligned}$$

Further, by KCL,

$$i_C = i_E - i_B = 1.618 \times 10^{-3} - 16 \times 10^{-6} = 1.602 \text{ mA}$$

3. Given that

$$(a) \quad \beta = \frac{\alpha}{1-\alpha} = \frac{0.987}{1-0.987} = \frac{0.987}{0.013} = \mathbf{75.92}$$

$$(b) \quad \alpha = \frac{\beta}{\beta+1} = \frac{120}{120+1} = \frac{120}{121} = \mathbf{0.992}$$

$$(c) \quad I_B = \frac{I_C}{\beta} = \frac{2 \text{ mA}}{180} = \mathbf{11.11 \mu A}$$

$$\begin{aligned}I_E &= I_C + I_B = 2 \text{ mA} + 11.11 \mu A \\&= \mathbf{2.011 \text{ mA}}\end{aligned}$$

4. Calculate the base current I_B required to switch a resistive load of 4 mA^2 .

$$I_B = \frac{I_C}{\beta} = \frac{4 \times 10^{-3}}{200} = 20 \mu A$$

Therefore, $\beta = 200$, $I_C = 4 \text{ mA}$ and $I_B = 20 \mu A$.

5. What will be the value of the base current into the transistor³.

$$I_B = \frac{V_B - V_{BE}}{R_B} = \frac{10 - 0.7}{100 \text{ k}\Omega} = 93 \mu A$$

6. Find the Q point. Given $V_{BB} = 2.5 \text{ V}$; $V_{CC} = 20 \text{ V}$, $R_E = 1.8 \text{ k}\Omega$, $R_C = 10 \text{ k}\Omega$.

² Source : https://www.electronics-tutorials.ws/transistor/tran_2.html

³ Source : https://www.electronics-tutorials.ws/transistor/tran_2.html

$$V_{BE} = 0.7 \text{ V}$$

$$V_E = V_{BB} - V_{BE} = 2.5 - 0.7 = 1.8 \text{ V}$$

$$I_E = V_E/R_E = 1 \text{ mA}$$

$$I_C = I_E = 1 \text{ mA} \text{ [Assumption } I_B=0\text{]}$$

$$V_C = V_{CC} - I_C R_C = 20 - (1 \times 10^{-3})(10 \times 10^3) = 10 \text{ V}$$

The Q point is (10 V, 1 mA).

7. what is the maximum base current?

Soln: $I_B = \frac{V_{BB} - V_{BE}}{R_B}$

I_B increases as R_B decreases So, $I_B \text{ max} = (10 - 0.7) / (470 - 5\%)$
 $= 9.3 / (446.5 \text{ K})$
 $= 0.208 \text{ } \mu\text{A}$

8. Transistor shown in the figure has $\beta = 300$ find, I_B

Soln:

$$I_B = \frac{V_{BB} - V_{BE}}{R_B}$$

$$= (10 - 0.7) / (1 \times 10^6)$$

$$= 9.3 \mu A$$

$$\beta = I_C / I_B$$

$$\text{So, } I_C = 2.79 \text{ mA}$$

$$V_{CE} = V_{CC} - I_C R_C$$

$$\text{So, } V_{CE} = 4.42 \text{ V}$$

$$P_D = V_{CE} I_C$$

$$\text{So, } P_D = 12.3 \text{ mW}$$

Transistor as a switch

9. find the value of the Base resistor (R_B) required to switch the load fully “ON” when the input terminal voltage exceeds 2.5V.⁴

$$R_B = \frac{V_{in} - V_{BE}}{I_B} = \frac{2.5 \text{ V} - 0.7 \text{ V}}{20 \times 10^{-6}} = 90 \text{ k}\Omega$$

10. Also calculate the new value of R_B .⁵

Transistor Base current:

$$I_B = \frac{I_C}{\beta} = \frac{200 \text{ mA}}{200} = 1 \text{ mA}$$

Transistor Base resistance:

$$R_B = \frac{V_{in} - V_{BE}}{I_B} = \frac{5.0 \text{ V} - 0.7 \text{ V}}{1 \times 10^{-3}} = 4.3 \text{ k}\Omega$$

⁴ Source : https://www.electronics-tutorials.ws/transistor/tran_4.html

⁵ Source: https://www.electronics-tutorials.ws/transistor/tran_4.html

Junction Field Effect Transistor

11. For the JFET Circuit⁶

$$(a) V_{GS_Q} = -V_{GG} = -2 \text{ V}$$

$$(b) I_{D_Q} = I_{DSS} \left(1 - \frac{V_{GS}}{V_P} \right)^2 = 10 \text{ mA} \left(1 - \frac{-2 \text{ V}}{-8 \text{ V}} \right)^2 \\ = 10 \text{ mA} (1 - 0.25)^2 = 10 \text{ mA} (0.75)^2 = 10 \text{ mA} (0.5625) \\ = \mathbf{5.625 \text{ mA}}$$

$$(c) V_{DS} = V_{DD} - I_D R_D = 16 \text{ V} - (5.625 \text{ mA})(2 \text{ k}\Omega) \\ = 16 \text{ V} - 11.25 \text{ V} = \mathbf{4.75 \text{ V}}$$

$$(d) V_D = V_{DS} = \mathbf{4.75 \text{ V}}$$

$$(e) V_G = V_{GS} = -2 \text{ V}$$

$$(f) V_S = \mathbf{0 \text{ V}}$$

12. A n-channel JFET

Numerical 01
A n-channel JFET has a drain current of 5mA. If $I_{DSS} = 10\text{mA}$ and $V_{GS(off)} = -6\text{V}$. Find value of
a) V_{GS} (Gate to source voltage)
b) V_P

Soln: a) $I_D = I_{DSS} \left(1 - \frac{V_{GS}}{V_{GS(off)}} \right)^2$
 $5\text{mA} = 10\text{mA} \left(1 + \frac{V_{GS}}{6} \right)^2$
 $\frac{1}{2} = \left(1 + \frac{V_{GS}}{6} \right)^2$
ie $1 + \frac{V_{GS}}{6} = \frac{1}{\sqrt{2}} = 0.707$
ie $V_{GS} = -1.757 \text{ V}$

b) $V_P = |V_{GS(off)}| = 6 \text{ V}$

⁶ For more Details : <https://home.kku.ac.th/rujchai/analog/FETBiasing.pdf>

Light Emitting Diode

13. An amber coloured LED⁷.

1). series resistor required at 10mA.

$$R_S = \frac{V_S - V_F}{I_F} = \frac{5\text{v} - 2\text{v}}{10\text{mA}} = \frac{3}{10 \times 10^{-3}} = 300\Omega$$

2). with a 100Ω series resistor.

$$R_S = \frac{V_S - V_F}{I_F}$$

$$\therefore I_F = \frac{V_S - V_F}{R_S} = \frac{5 - 2}{100} = 30\text{mA}$$

⁷ For more Details : https://www.electronics-tutorials.ws/diode/diode_8.html

Operational Amplifiers

14. Determine the output level

- (a) Maximum negative
- (b) Maximum positive
- (c) Maximum negative

15. Draw the output voltage waveform

